

	Type	Hits	Search Text	DBs
1	BRS	454250	oxide spacer	USPAT
2	BRS	101438	TiN titanium adj nitride	USPAT
3	BRS	2659	(anti-reflective adj (layer coating)) antireflective adj (layer coating)	USPAT
4	BRS	740	(TiN titanium adj nitride) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating))	USPAT
5	IS&R	1400	("438/250,253,254,393,396,397").CCLS.	USPAT
6	BRS	6	((TiN titanium adj nitride) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating))) and ("438/250,253,254,393,396,397").CCLS.)	USPAT
7	IS&R	1639	((("438/149,151,157,166,152,399,255,398,665,964") or ("257/68,307,309,437"))).CCLS.	USPAT
8	BRS	26	((("438/149,151,157,166,152,399,255,398,665,964") or ("257/68,307,309,437"))).CCLS.) and ((TiN titanium adj nitride) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating)))	USPAT
9	BRS	32	((((TiN titanium adj nitride) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating))) and ("438/250,253,254,393,396,397").CCLS.) or (((("438/149,151,157,166,152,399,255,398,665,964") or ("257/68,307,309,437"))).CCLS.) and ((TiN titanium adj nitride) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating))))	USPAT
10	BRS	1919	((anti-reflective adj (layer coating)) antireflective adj (layer coating)) not (TiN titanium adj nitride)	USPAT

	Time Stamp	Comments	Error Definition	Errors
1	2000/09/26 11:23			0
2	2000/09/26 11:28			0
3	2000/09/26 11:43			0
4	2000/09/26 13:18			0
5	2000/09/26 11:36			0
6	2000/09/26 11:39			0
7	2000/09/26 11:42			0
8	2000/09/26 11:42			0
9	2000/09/27 13:43			0
10	2000/09/26 13:02			0

	Type	Hits	Search Text	DBs
11	BRS	6	((("438/250,253,254,393,396,397").CCLS.) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating)) not (TiN titanium adj nitride))	USPAT
12	BRS	34	((("438/149,151,157,166,152,399,255,398,665,964") or ("257/68,307,309,437")).CCLS.) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating)) not (TiN titanium adj nitride))	USPAT
13	BRS	133	(stacked near capacitor) and (planar near capacitor)	USPAT
14	BRS	2045	(stacked near capacitor) or (planar near capacitor)	USPAT
15	BRS	423	((stacked near capacitor) or (planar near capacitor)) and (TiN titanium adj nitride)	USPAT
16	BRS	4	((stacked near capacitor) or (planar near capacitor)) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating))	USPAT
17	BRS	121	((stacked near capacitor) or (planar near capacitor)) and (TiN titanium adj nitride) and spacer	USPAT
18	BRS	14	(((((stacked near capacitor) or (planar near capacitor)) and (TiN titanium adj nitride)) and spacer) and oxide) and (oxide near spacer)	USPAT
19	BRS	340	(upper adj electrode) and (capacitor adj dielectric) and (lower adj electrode)	USPAT
20	BRS	155	((upper adj electrode) and (capacitor adj dielectric) and (lower adj electrode)) and ((anti-reflective adj (layer coating)) antireflective adj (layer coating)) or (TiN titanium adj nitride))	USPAT
21	BRS	115	(upper adj electrode) and (capacitor adj dielectric) and (lower adj electrode)	EPO; JPO; Derwent; IBM TDB
22	BRS	115	(upper adj electrode) and (capacitor adj dielectric) and (lower adj electrode)	EPO; JPO; Derwent; IBM TDB

	Time Stamp	Comments	Error Definition	Errors
11	2000/09/26 13:04			0
12	2000/09/26 13:17			0
13	2000/09/26 13:18			0
14	2000/09/26 13:18			0
15	2000/09/26 13:19			0
16	2000/09/26 13:22			0
17	2000/09/26 13:22			0
18	2000/09/26 13:23			0
19	2000/09/26 15:18			0
20	2000/09/26 13:36			0
21	2000/09/27 16:36			0
22	2000/09/27 09:13			0

	Type	Hits	Search Text	DBs
23	BRS	95170	Watanabe	JPO
24	BRS	11766	Akiyoshi	JPO
25	BRS	276	Watanabe and Akiyoshi	JPO
26	BRS	178528	fujitsu	JPO
27	BRS	14	(Watanabe and Akiyoshi) and fujitsu	JPO
28	BRS	32506	WATANABE WATANABE-AKITOSHI WATANABE-AKIYOSHI	USPAT
29	BRS	5140	semiconductor and (WATANABE WATANABE-AKITOSHI WATANABE-AKIYOSHI)	USPAT
30	BRS	1408	capacitor and (semiconductor and (WATANABE WATANABE-AKITOSHI WATANABE-AKIYOSHI))	USPAT
31	BRS	18	((upper adj electrode) and (capacitor adj dielectric) and (lower adj electrode)) and (capacitor and (semiconductor and (WATANABE WATANABE-AKITOSHI WATANABE-AKIYOSHI)))	USPAT
32	BRS	60	((upper adj electrode) and (dielectric) and (lower adj electrode)) and (capacitor and (semiconductor and (WATANABE WATANABE-AKITOSHI WATANABE-AKIYOSHI)))	USPAT
33	IS&R	256	("438/595").CCLS.	USPAT
34	BRS	46	capacitor and (("438/595").CCLS.)	USPAT
35	IS&R	3	(("5005103") or ("5356826") or ("5618749")).PN.	USPAT
36	BRS	340	(upper adj electrode) and (capacitor adj dielectric) and (lower adj electrode)	USPAT

	Time Stamp	Comments	Error Definition	Errors
23	2000/09/27 08:55			0
24	2000/09/27 08:55			0
25	2000/09/27 08:56			0
26	2000/09/27 08:56			0
27	2000/09/27 10:52			0
28	2000/09/27 09:10			0
29	2000/09/27 09:11			0
30	2000/09/27 09:11			0
31	2000/09/27 09:15			0
32	2000/09/27 09:15			0
33	2000/09/27 10:52			0
34	2000/09/27 11:11			0
35	2000/09/27 13:40			0
36	2000/09/28 14:50			0